KB814

GENERAL PURPOSE
HIGH ISOLATION VOLTAGE
SINGLE TRANSISTOR TYPE
PHOTOCOUPLER SERIES

FEATURES

1.AC Input

2.High isolation voltage between input and output (Viso=5000 Vrms)

3.Compact dual-in-line package

KB814:1-channel type

4.Recognized by UL and CUL, file NO. E225308

5. Approved by VDE 0884 Teil2(NO:40006364)
(Creepage distance between input and output:7mm or more)

DESCRIPTION

1.The KB814(1-channel) is optically coupled isolators containing two GaAs light emitting diode and an NPN silicon phototransistor.

2.The lead pitch is 2.54mm.

APPLICATIONS

1.Computer terminals.

2.Registers, copiers, automatic vending machines.

3.System appliances, measuring instruments.

4.Programmable logic controller.

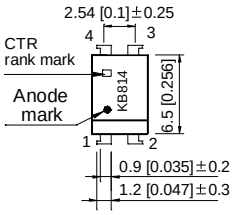
5.Signal transmission between circuits of different potentials and impedances.

*PACKAGE DIMENSIONS (UNIT:mm)

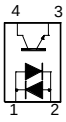
DIP Type

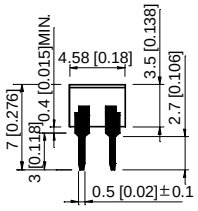
KB814

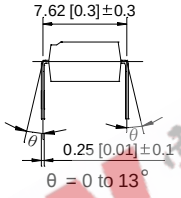
Top View



Internal connection diagram







1. Anode,Cathode
2. Anode,Cathode
3. Emitter
4. Collector

TOLERANCE : ±0.5[±0.02] UNLESS OTHERWISE NOTED.

* Absolute Maximum Ratings (Ta=25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	IF	± 50	mA
	Power dissipation	P	70	mW
Output	Collector-emitter voltage	V_{CEO}	35	V
	Emitter-collector voltage	V_{ECO}	6	V
	Collector current	I_C	50	mA
	Collector power dissipation	P_C	150	mW
Total power dissipation		Ptot	200	mW
*1 Isolation voltage		Viso	5000	V_{rms}
Operating temperature		Topr	-30~+100	° C
Storage temperature		Tstg	-55~+125	° C
*2 Soldering temperature		Tsol	260	° C

*1 40 to 60%RH, AC for 1 minute

*2 For 10 seconds

* Electro-optical Characteristics (Ta=25°C)

Parameter			Symbol	Conditions	Min.	Typ.	Max.	Unit
Input	Forward voltage		V_F	I_F=± 20mA	—	1.2	1.4	V
	Peak forward voltage		V_{FM}	I_{FM}=± 0.5A	—	—	3.0	V
Output	Collector dark current		I_{CEO}	V_{CE}=20V,I_F=0mA	—	—	10^{-7}	A
Transfer charact-eristics	*1 Current transfer ratio		CTR	I_F=± 1mA, V_{CE}=5V	20	—	300	%
	Collector-emitter saturation voltage		$V_{CE(sat)}$	I_F=± 20mA, I_C=1mA	—	0.1	0.2	V
	Response time	Rise time	t_r	V_{CE}=2V, I_C=2mA R_L=100Ω	—	4	18	μS
		Fall time	t_f		—	3	18	μS

*1 Classification table of current transfer ratio is shown below.

$$CTR=\frac{Ic}{I_F}\ X\ 100\%$$

Model NO.	Rank mark	CTR(%)
KB814L	L	20~60
KB814A	A	50~150
KB814B	B	120~300
KB814LA	L or A	20~150
KB814AB	A or B	50~300
KB814	L,A,B or No mark	20~300

Fig. 1 Current Transfer Ratio vs. Forward Current

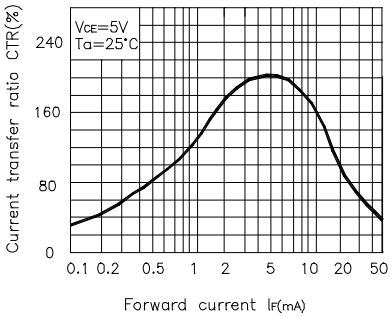


Fig. 2 Forward Current vs. Forward voltage

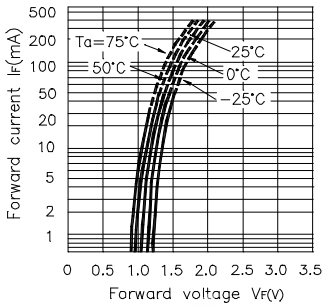


Fig. 3 Collector Current vs. Collector-emitter Voltage

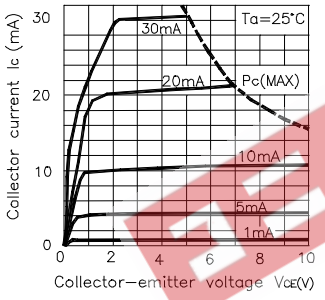


Fig. 4 Relative Current Transfer Ratio vs. Ambient Temperature

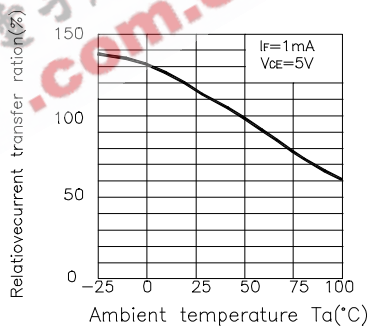


Fig. 5 Collector-emitter Saturation Voltage vs. Ambient Temperature

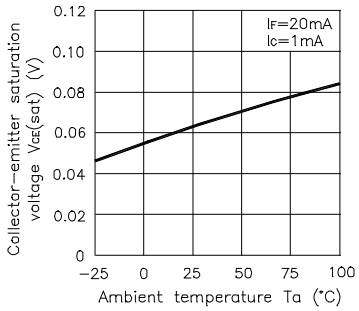


Fig. 6 Collector Dark Current vs. Ambient Temperature

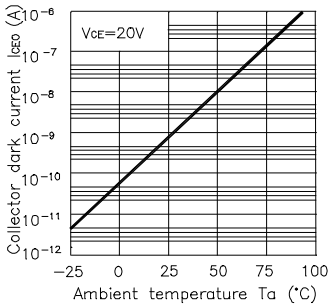


Fig. 7 Forward Current vs. Ambient Temperature

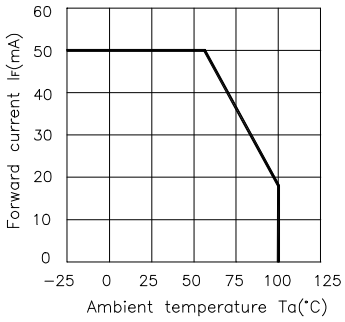


Fig. 8 Collector Power Dissipation vs. Ambient Temperature

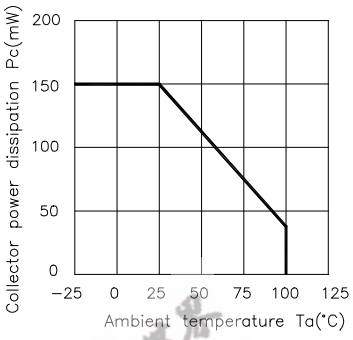
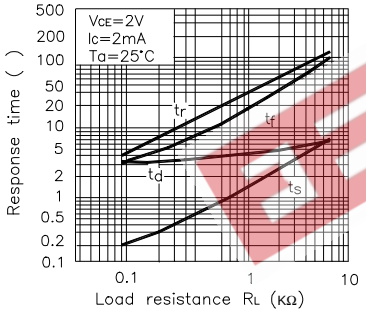


Fig. 9 Response Time vs. Load Resistance



Test Circuit for Response Time

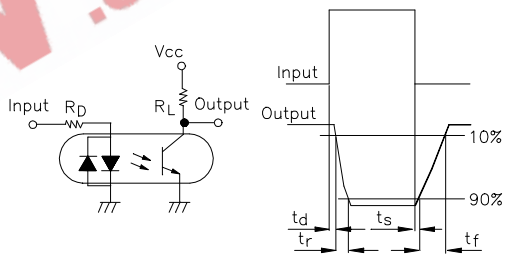
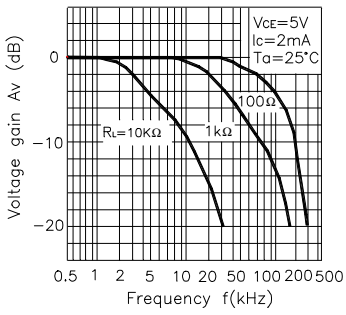


Fig. 10 Frequency Response



Test Circuit for Frequency Response

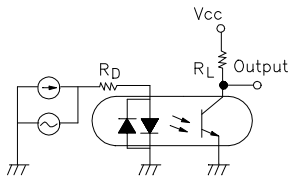
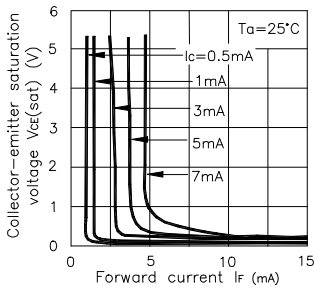


Fig. 11 Collector-emitter Saturation Voltage vs. Forward Current



* NOTES ON HANDLING

1.Recommended soldering conditions (Dip soldering)

(1) Dip soldering

Temperature	260 °C or below (molten solder temperature)
Time	Less than 10 seconds.
Cycle	One cycle allowed to be dipped in solder including plastic nold portion.
Flux	Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

(2) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2.Cautions regarding noise

Be aware that power is suddenly into the component any surge current may cause damage happen, even if the voltage is within the absolute maximum ratings.

CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested.

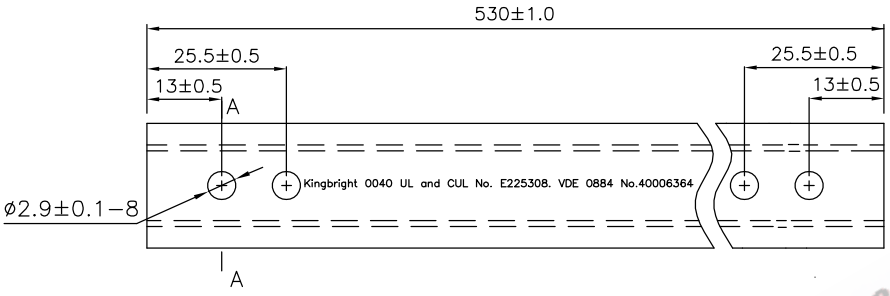
GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them.

RESTRICTIONS ON PRODUCT USE

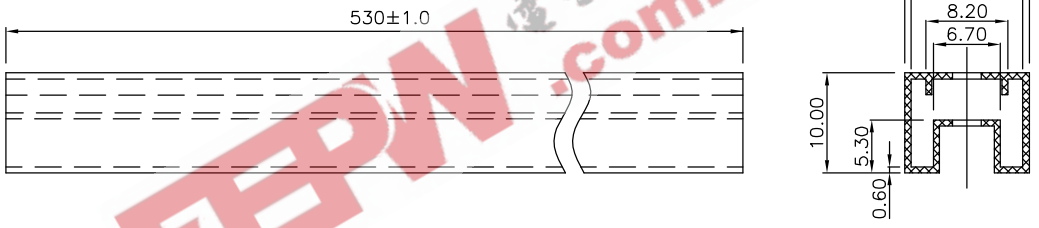
- The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version. Not all devices / types available in every country.
- We are mention about our product quality stablity, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing KINGBRIGHT products, to observe standards of safety, and to a avoid situations in which a malfunction or failure of a KINGBRIGHT product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that KINGBRIGHT products are used within specified operating ranges as set forth in the most recent products specifications.

Dimension of Tube

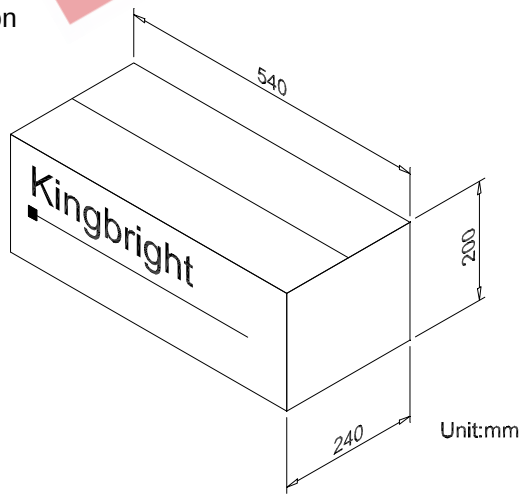
TOLERANCE : ± 0.4[± 0.012] UNLESS OTHERWISE NOTED.
Unit:mm



A–A Side view



Dimension of Carton



Unit:mm

Part Number	Package	Packing Style
KB814	4-pin DIP	100pcs / each tube